



Product Summary (@T_A = +25°C)

V _{RRM} (V)	I ₀ (A)	V _F Max (V)	I _R Max (μA)
600	2	1.7	5

Description

The US2JDF is a rectifier packaged in the low profile D-FLAT package. Providing ultra-fast recovery time for high efficiency, this device is ideal for use in general rectification applications.

Applications

- Switching Mode Power Supplies
- Chargers
- LED lightings
- Inverters
- AC-DC Adapters

2.0A SURFACE MOUNT ULTRA-FAST RECTIFIER

Features and Benefits

- Glass Passivated Die Construction
- Ultra-Fast Recovery Time for High Efficiency
- Surge Overload Rating to 50A Peak
- High Current Capability
- Low Profile Design, Package Height less than 1.1mm
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standard for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>US2JDFQ</u>)

Mechanical Data

- Case: D-FLAT
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (€3)
- Polarity: Cathode Band
- Weight: 0.036 grams (Approximate)

D-FLAT



Top View

Ordering Information (Note 4)

Part Number	Qualification	Case	Packaging
US2JDF-13	AEC-Q101	D-FLAT	10,000/Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

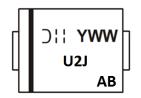
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



U2J= Product Type Marking Code)'' = Manufacturer's Code Marking YWW = Date Code Marking Y = Last Digit of Year (ex: 6 for 2016) WW = Week Code (01 to 53) AB = Foundry and Assembly Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase,	half wave,	60Hz,	resistive	or inductive load.
				000/

For capacitance load, derate current by 20	%.			
Characteristic		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage (Note 5)		V _{RRM} V _{RWM} Vr	600	v
RMS Reverse Voltage		V _{R(RMS)}	420	V
Average Rectified Output Current	@ T _A = +25°C	lo	2.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I _{FSM}	50	А

Thermal Characteristics

Notes:

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Terminal	R _{0JT}	22	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

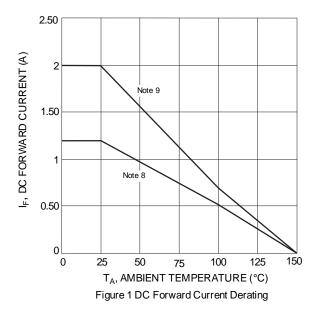
Characteristic		Symbol	Value	Unit
Minimum Reverse Breakdown Voltage (Note 5)	@I _R = 5μA	V _{(BR)R}	600	V
Maximum Forward Voltage Drop @ I _F = 2.0A		VF	1.7	V
Peak Reverse Current at Rated DC Blocking Voltage (Note 5)	@ T _A = +25°C @ T _A = +100°C		5.0 100	μA
Maximum Reverse Recovery Time (Note 6)		t _{rr}	75	ns
Typical Total Capacitance (Note 7)		Ст	10	pF

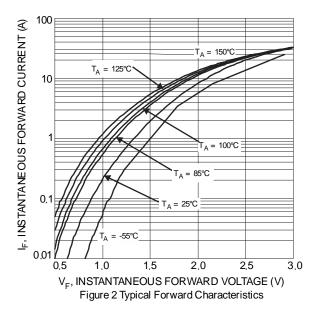
5. Short duration pulse test used to minimize self-heating effect.

6. Measured with I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A. See Figure 7.

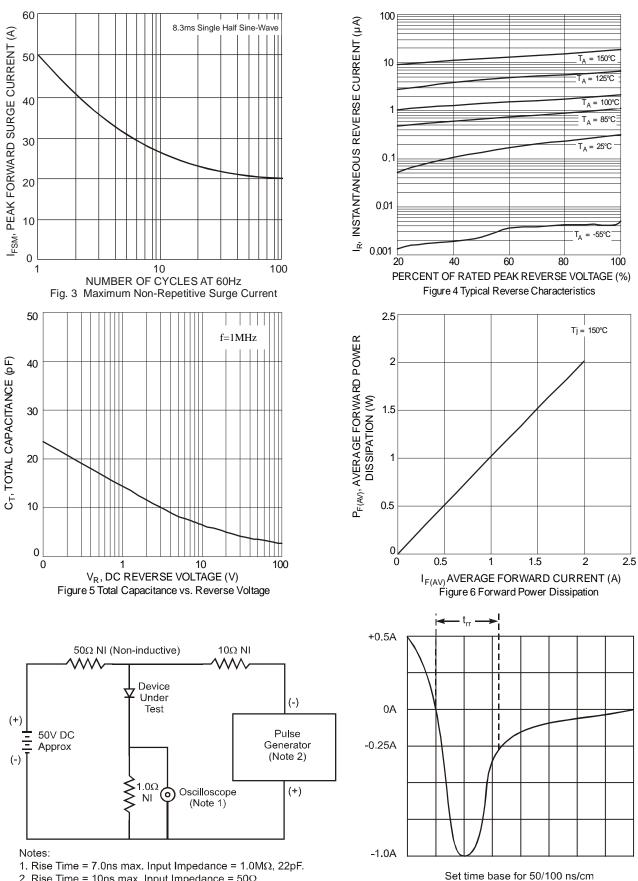
7. Measured at f=1.0MHz and applied reverse voltage of 4.0V DC.

Bovice mounted on FR-4 substrate, 1in.*1in., 202, single-sided, PC boards with 0.1in.*0.15in. copper pads.
Device mounted on FR-4 substrate, 0.4in.*0.5in., 202, single-sided, PC boards with 0.2in.*0.25in. copper pads.









2. Rise Time = 10ns max. Input Impedance = 50Ω .

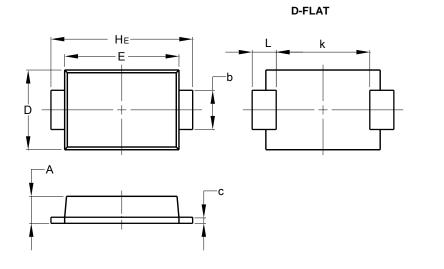
Fig. 7 Reverse Recovery Time Characteristic and Test Circuit 3 of 5

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Package Outline Dimensions

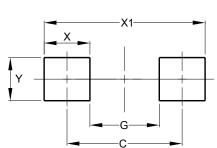
Please see http://www.diodes.com/package-outlines.html for the latest version.



D-FLAT					
Dim	Min	Max			
Α	0.90	1.10			
b	1.25	1.65			
С	0.10	0.40			
D	2.25	2.95			
Е	3.95	4.60			
k	2.80	I			
HE	5.00	5.60			
L 0.50 1.30					
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



D-FLAT

Dimensions	Value (in mm)
С	4.65
G	2.80
Х	1.85
X1	6.50
Y	1.70



US2JDF

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